



Parameter	Rating	Units
Relay Blocking Voltage	350	V
Relay Load Current	120	$\text{mA}_{\text{rms}} / \text{mA}_{\text{DC}}$
Relay On-Resistance (max)	20	Ω
Bridge Rectifier Reverse Voltage	100	V
Darlington Collector Current	120	mA
Darlington Current Gain	10,000	-

Features

- Current Limiting
- 3750V_{rms} Input/Output Isolation
- 2mW Hook Switch Drive Power (Logic Compatible)
- Full-Wave Bridge Rectifier
- Darlington Transistor for Electronic Inductor "Dry" Circuits
- Full-Wave Current Detector for Ring Signal or Loop Current Detect
- JEDEC Standard Lead Configuration
- No Moving Parts
- Board Space and Cost Savings
- Small 16-Pin SOIC Package (PCMCIA Compatible)

Applications

- Data/Fax Modem
- Voice Mail Systems
- Telephone Sets
- Computer Telephony Integration
- Set Top Box Modems

Description

The Integrated Telecom Circuit combines a single-pole, normally open (1-Form-A) solid state relay, a bridge rectifier, a Darlington transistor, and an optocoupler into one 16-pin SOIC package, consolidating designs and reducing component count in telecom applications. The ITC117PL's relay features the added benefit of current limiting, and the optocoupler provides for full-wave detection of ring signals.

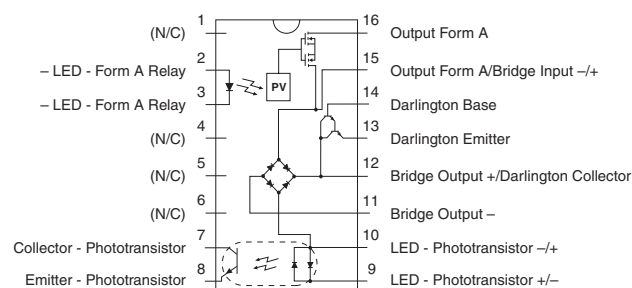
Approvals

- UL Recognized Component: File E76270
- CSA Certified Component: Certificate 1305490
- EN/IEC 60950-1 Certified Component:
TUV Certificate: B 12 11 82667 002

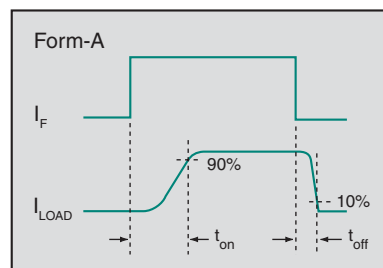
Ordering Information

Part #	Description
ITC117PL	16-Pin SOIC (50/Tube)
ITC117PLTR	16-Pin SOIC (1000/Reel)

Pin Configuration



Switching Characteristics of Normally Open Devices



Absolute Maximum Ratings @ 25°C

Parameter	Ratings	Units
Input Control Current, Relay	50	mA
Input Control Current, Detector	100	mA
Total Package Dissipation ¹	1	W
Isolation Voltage, Input to Output	3750	V _{rms}
Operational Temperature	-40 to +85	°C
Storage Temperature	-40 to +125	°C

¹ Derate linearly 8.33 mW / °C

Total Power Dissipation (PD):

$$P_D = P_{\text{HOOKSWITCH}} + P_{\text{BRIDGE}} + P_{\text{DARLINGTON}} + P_{\text{LED}}$$

$$P_D = (R_{DS(on)})(I_F^2) + 2(V_F)(I_L) + (V_{CE})(I_L) + (V_{LED})(I_F)$$

WHERE:

$R_{DS(on)}$ = Maximum relay on-resistance

I_L = Maximum loop current

V_F = Maximum diode forward voltage

V_{CE} = Maximum voltage collector to emitter

V_{LED} = Maximum LED forward voltage

I_F = Maximum LED current

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

Electrical Characteristics @25°C: Relay Section

Parameter	Conditions	Symbol	Min	Typ	Max	Units
Output Characteristics						
Blocking Voltage (Peak)	-	V_L	-	-	350	V_P
Load Current, Continuous	-	I_L	-	-	120	$\text{mA}_{\text{rms}} / \text{mA}_{\text{DC}}$
On-Resistance	$I_L = 120\text{mA}$	R_{ON}	-	-	20	Ω
Off-State Leakage Current	$V_L = 350V_P, T_J = 25^\circ\text{C}$	I_{LEAK}	-	-	1	μA
Switching Speeds						
Turn-On	$I_F = 5\text{mA}, V_L = 10V$	t_{on}	-	-	5	ms
Turn-Off		t_{off}	-	-	3	ms
Output Capacitance	$V_L = 50V, f = 1\text{MHz}$	C_{OUT}	-	25	-	pF
Current Limit	$I_F = 5\text{mA}$	I_{CL}	190	235	280	mA
Input Characteristics						
Input Control Current to Activate	$I_L = 120\text{mA}$	I_F	-	-	5	mA
Input Voltage Drop	$I_F = 5\text{mA}$	V_F	0.9	1.2	1.4	V
Reverse Input Voltage	-	V_R	-	-	5	V
Reverse Input Current	$V_R = 5V$	I_R	-	-	10	μA

Electrical Characteristics @25°C: Detector Section

Parameter	Conditions	Symbol	Min	Typ	Max	Units
Output Characteristics						
Phototransistor Blocking Voltage	$I_C=10\mu A$	BV_{CEO}	20	50	-	V
Phototransistor Dark Current	$V_{CE}=5V, I_F=0mA$	I_{CEO}	-	50	500	nA
Saturation Voltage	$I_C=2mA, I_F=16mA$	V_{SAT}	-	0.3	0.5	V
Current Transfer Ratio	$I_F=6mA, V_{CE}=0.5V$	CTR	33	400	-	%
Input Characteristics						
Input Control Current	$I_C=2mA, V_{CE}=0.5V$	I_F	-	2	6	mA
Input Voltage Drop	$I_F=5mA$	V_F	0.9	1.2	1.4	V
Input Current (Detector Must be Off)	$I_C=1\mu A, V_{CE}=5V$	I_F	5	25	-	μA

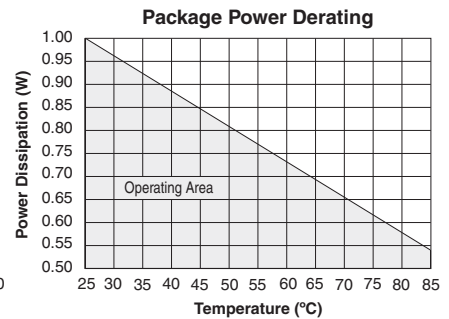
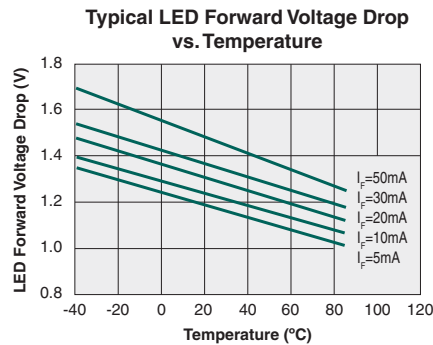
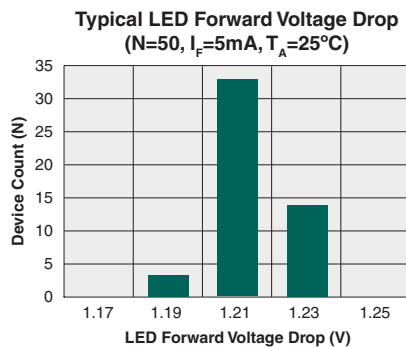
Electrical Characteristics @25°C (Unless Otherwise Noted): Bridge Rectifier Section

Parameter	Conditions	Symbol	Min	Typ	Max	Units
Reverse Voltage	-	V_{RD}	-	-	100	V
Forward Voltage Drop	$I_{FD}=120mA$	V_{FD}	-	-	1.5	V
Reverse Leakage Current	$T_J=25^\circ C, V_R=100V$	I_{RD}	-	-	10	μA
	$T_J=85^\circ C$		-	50	-	
Forward Current	-	I_{FD}	-	-	140	mA
Continuous	-		-	-	140	
Peak	$t=10ms$		-	-	500	

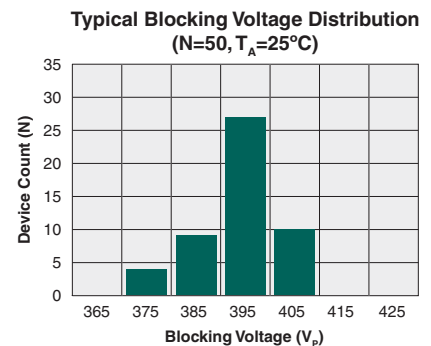
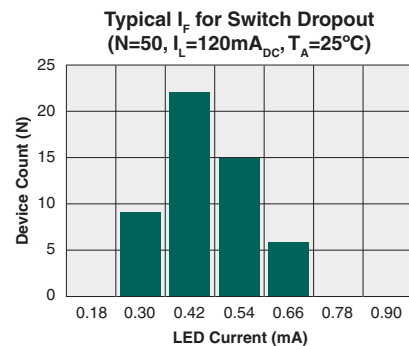
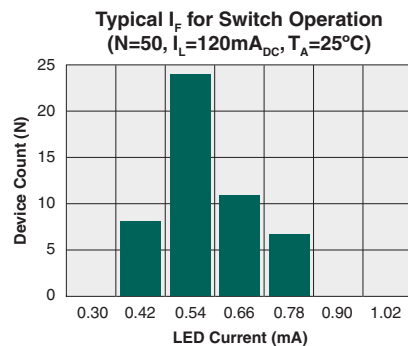
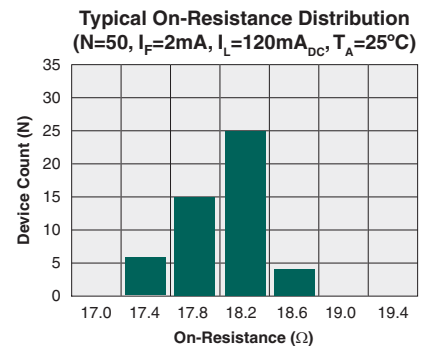
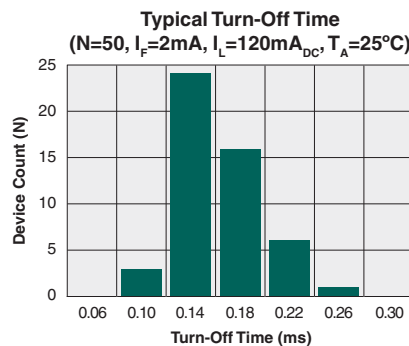
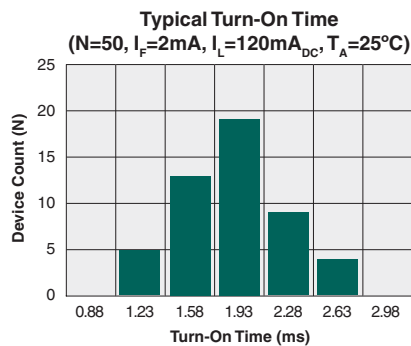
Electrical Characteristics @25°C: Darlington Transistor Section

Parameter	Conditions	Symbol	Min	Typ	Max	Units
Collector-Emitter Voltage	$I_C=10mA_{DC}, I_B=0mA$	V_{CEO}	40	-	-	V
Collector Current, Continuous	$V_{CE}=3.5V$	I_C	-	-	120	mA
Power Dissipation	-	P_D	-	-	500	mW
Off-State Collector-Emitter Leakage Current	$V_{CE}=10V, I_B=0mA$	I_{CEX}	-	-	1	μA
DC Current Gain	$V_{CE}=10V_{DC}, I_C=120mA$	h_{FE}	10,000	-	-	-
Saturation Voltage	$I_C=120mA$	$V_{CE(sat)}$	-	-	1.5	V
Total Harmonic Distortion	$I_C=40mA, f_O=300Hz @ -10dBm$	-	-	-	-80	dB

DEVICE PERFORMANCE DATA*

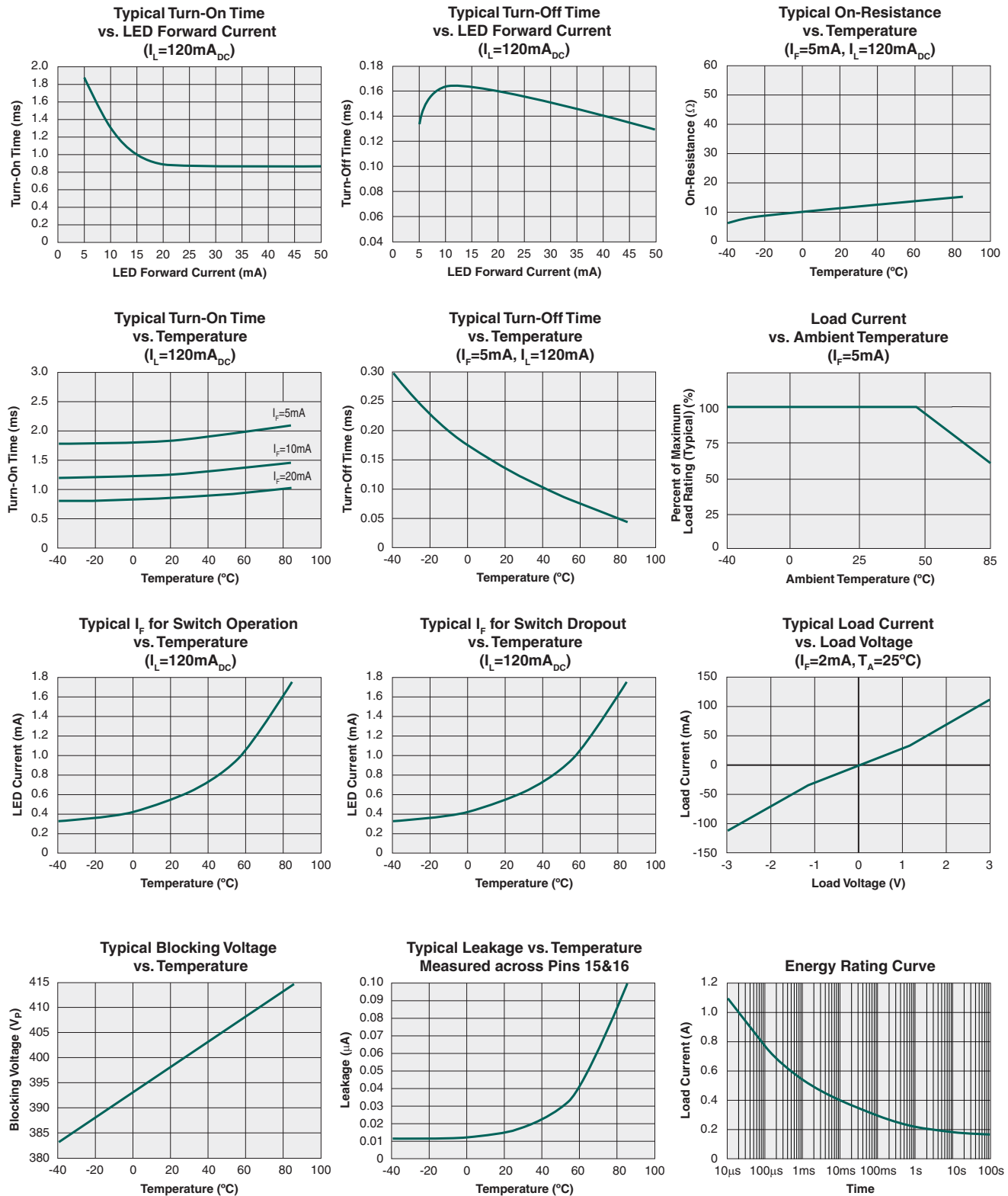


RELAY PERFORMANCE DATA*



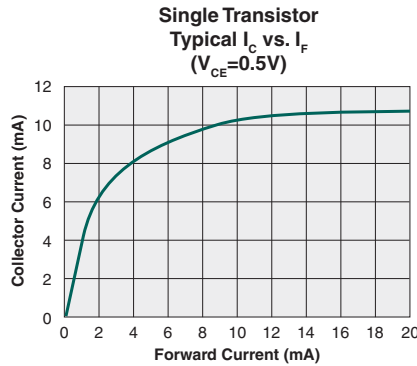
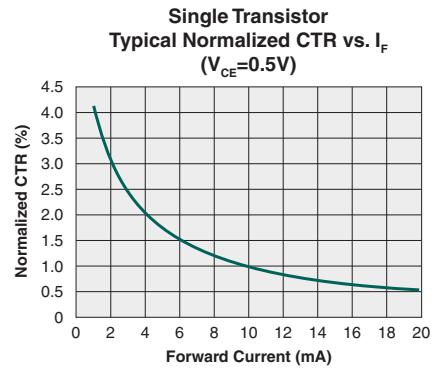
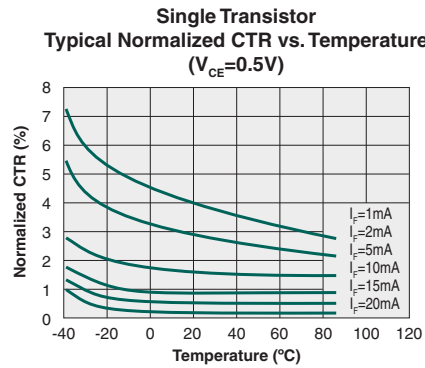
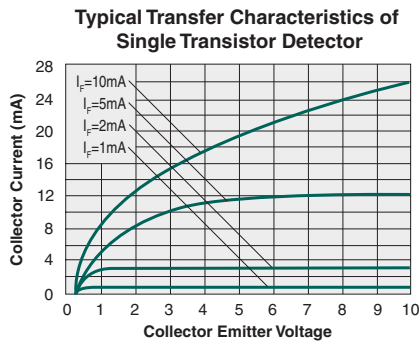
* The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

RELAY PERFORMANCE DATA (cont)*

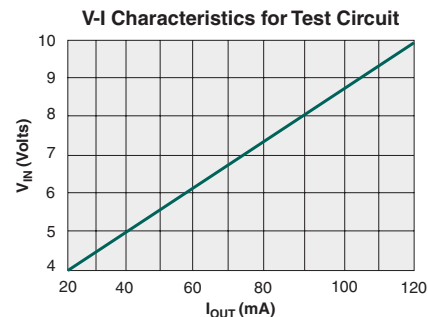
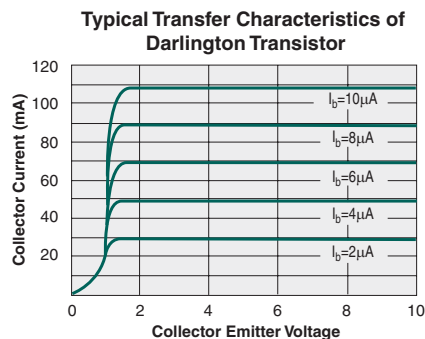
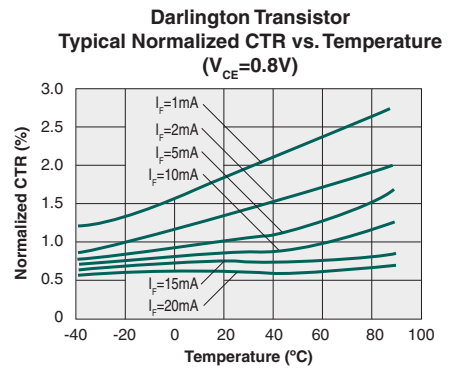
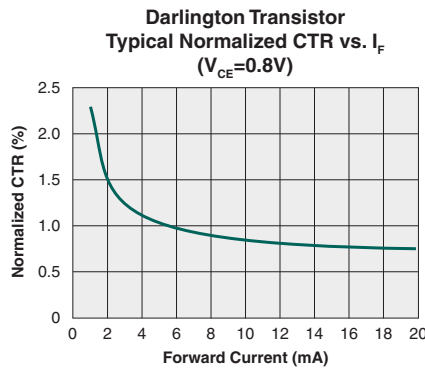
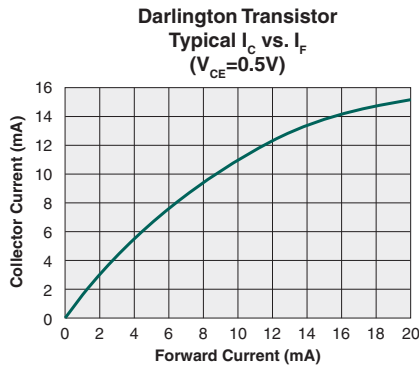


* The Performance data shown in the graphs above is typical of device performance. For guaranteed parameters not indicated in the written specifications, please contact our application department.

PHOTOTRANSISTOR PERFORMANCE DATA*



DARLINGTON PERFORMANCE DATA*



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Manufacturing Information

Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. IXYS Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL) rating** as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Rating
ITC117PL	MSL 1

ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

Reflow Profile

This product has a maximum body temperature and time rating as shown below. All other guidelines of **J-STD-020** must be observed.

Device	Maximum Temperature x Time
ITC117PL	260°C for 30 seconds

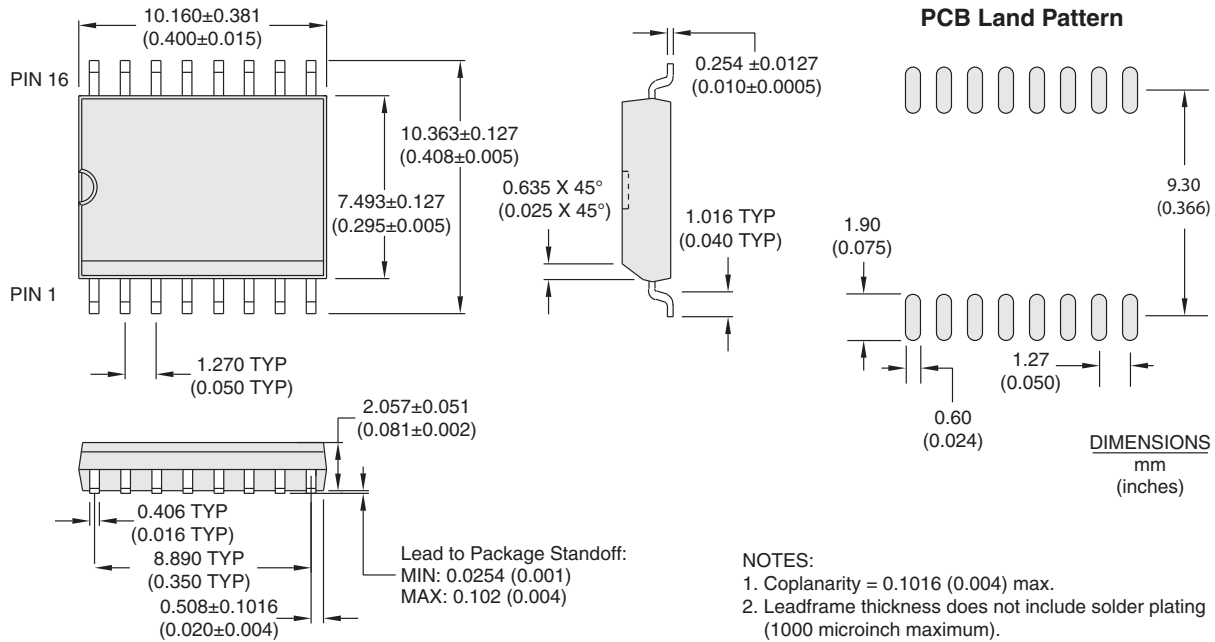
Board Wash

IXYS Integrated Circuits Division recommends the use of no-clean flux formulations. However, board washing to remove flux residue is acceptable. Since IXYS Integrated Circuits Division employs the use of silicone coating as an optical waveguide in many of its optically isolated products, the use of a short drying bake could be necessary if a wash is used after solder reflow processes. Chlorine- or Fluorine-based solvents or fluxes should not be used. Cleaning methods that employ ultrasonic energy should not be used.

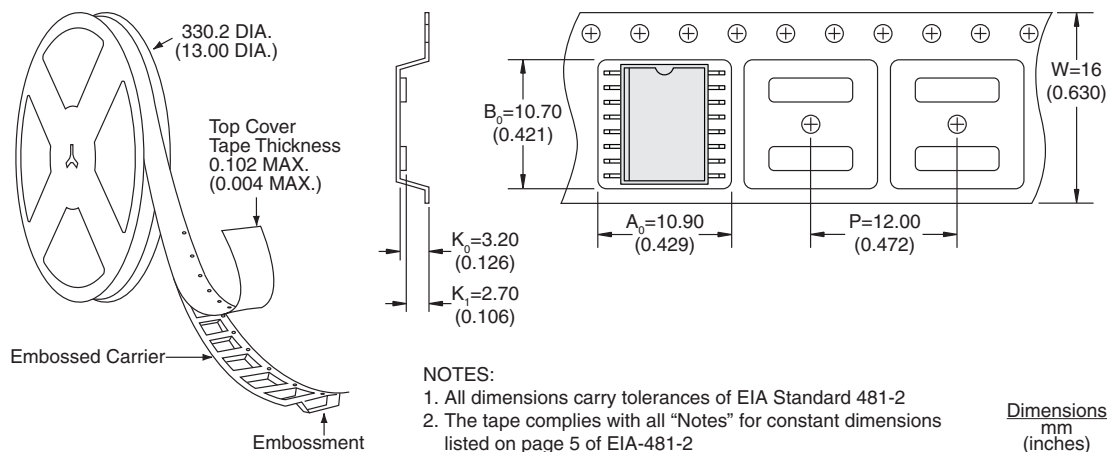


MECHANICAL DIMENSIONS

ITC117PL



ITC117PLTR Tape & Reel



For additional information please visit our website at: www.ixysic.com

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